

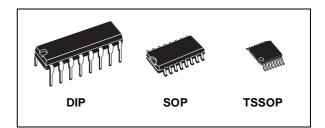
12 STAGE BINARY COUNTER

- HIGH SPEED : funy = 70 MHz (7)
- $f_{MAX} = 70 \text{ MHz} (TYP.) \text{ at } V_{CC} = 6V$ • LOW POWER DISSIPATION: $I_{CC} = 4\mu A(MAX.) \text{ at } T_A = 25^{\circ}C$
- HIGH NOISE IMMUNITY: $V_{NIH} = V_{NIL} = 28 \% V_{CC}$ (MIN.)
- SYMMETRICAL OUTPUT IMPEDANCE: |I_{OH}| = I_{OL} = 4mA (MIN)
- BALANCED PROPAGATION DELAYS: t_{PLH} ≅ t_{PHL}
- WIDE OPERATING VOLTAGE RANGE: V_{CC} (OPR) = 2V to 6V
- PIN AND FUNCTION COMPATIBLE WITH 74 SERIES 4040

DESCRIPTION

The M74HC4040 is an high speed CMOS 12 STAGE BINARY COUNTER fabricated with silicon gate C²MOS technology.

A clear input is used to reset the counter to the all low level state. A high level on CLEAR accomplishes the reset function. A negative



ORDER CODES

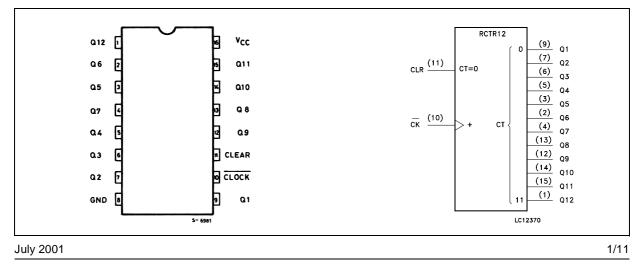
PACKAGE	TUBE	T & R
DIP	M74HC4040B1R	
SOP	M74HC4040M1R	M74HC4040RM13TR
TSSOP		M74HC4040TTR

transition on the CLOCK input increments the counter by one.

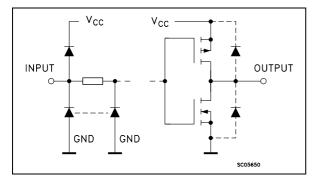
For M74HC4040 each division stage has an output; the final frequency is 1/4096 $f_{\rm IN}.$

All inputs are equipped with protection circuits against static discharge and transient excess voltage.

PIN CONNECTION AND IEC LOGIC SYMBOLS



INPUT AND OUTPUT EQUIVALENT CIRCUIT



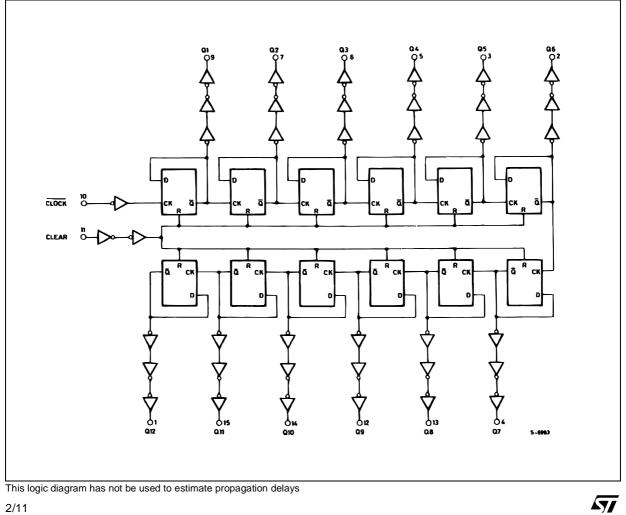
PIN DESCRIPTION

PIN No	SYMBOL	NAME AND FUNCTION			
9, 7, 6, 5, 3, 2, 4, 13, 12, 14, 15, 1	Q1 to Q12	Parallel Outputs			
10	CLOCK	Clock Input (LOW to HIGH, Edge Triggered)			
11	CLEAR	Reset Inputs			
8	GND	Ground (0V)			
16	Vcc	Positive Supply Voltage			

TRUTH TABLE

CLOCK	CLEAR	OUTPUT STATE
X	Н	ALL OUTPUTS = "L"
	L	NO CHANGE
	L	ADVANCE TO NEXT STATE

LOGIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V _{CC}	Supply Voltage	-0.5 to +7	V
VI	DC Input Voltage	-0.5 to V _{CC} + 0.5	V
V _O	DC Output Voltage	-0.5 to V _{CC} + 0.5	V
Ι _{ΙΚ}	DC Input Diode Current	± 20	mA
I _{OK}	DC Output Diode Current	± 20	mA
۱ ₀	DC Output Current	± 25	mA
I _{CC} or I _{GND}	DC V _{CC} or Ground Current	± 50	mA
PD	Power Dissipation	500(*)	mW
T _{stg}	Storage Temperature	-65 to +150	°C
ΤL	Lead Temperature (10 sec)	300	°C

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these conditions is not implied (*) 500mW at 65 °C; derate to 300mW by 10mW/°C from 65°C to 85°C

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter		Value	Unit
V _{CC}	Supply Voltage		2 to 6	V
VI	Input Voltage		0 to V _{CC}	V
Vo	Output Voltage		0 to V _{CC}	V
T _{op}	Operating Temperature		-55 to 125	°C
	Input Rise and Fall Time	$V_{CC} = 2.0V$	0 to 1000	ns
t _r , t _f		$V_{CC} = 4.5V$	0 to 500	ns
		$V_{CC} = 6.0V$	0 to 400	ns



DC SPECIFICATIONS

		1	Test Condition				Value				
Symbol	Parameter	v _{cc}		т	T _A = 25°C		-40 to 85°C		-55 to 125°C		Unit
		(V)		Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
V _{IH}	High Level Input	2.0		1.5			1.5		1.5		
	Voltage	4.5		3.15			3.15		3.15		V
		6.0		4.2			4.2		4.2		
V _{IL}	Low Level Input	2.0				0.5		0.5		0.5	
	Voltage	4.5				1.35		1.35		1.35	V
		6.0				1.8		1.8		1.8	
V _{OH}	High Level Output	2.0	I _O =-20 μA	1.9	2.0		1.9		1.9		
	Voltage	4.5	I _O =-20 μA	4.4	4.5		4.4		4.4		
		6.0	I _O =-20 μA	5.9	6.0		5.9		5.9		V
		4.5	I _O =-4.0 mA	4.18	4.31		4.13		4.10		
		6.0	I _O =-5.2 mA	5.68	5.8		5.63		5.60		
V _{OL}	Low Level Output	2.0	I _O =20 μA		0.0	0.1		0.1		0.1	
	Voltage	4.5	I _O =20 μA		0.0	0.1		0.1		0.1	
		6.0	I _O =20 μA		0.0	0.1		0.1		0.1	V
		4.5	I _O =4.0 mA		0.17	0.26		0.33		0.40	
		6.0	I _O =5.2 mA		0.18	0.26		0.33		0.40	
I	Input Leakage Current	6.0	$V_{I} = V_{CC}$ or GND			± 0.1		± 1		± 1	μΑ
I _{CC}	Quiescent Supply Current	6.0	$V_{I} = V_{CC}$ or GND			4		40		80	μΑ

		Т	est Condition				Value				
Symbol	Parameter	v _{cc}		т	A = 25°	C	-40 to	85°C	-55 to 125°C		Unit
		(V)		Min.	Тур.	Max.	Min.	Max.	Min.	Max.	
t _{TLH} t _{THL}	Output Transition	2.0			30	75		95		110	
	Time	4.5			8	15		19		22	ns
		6.0			7	13		16		19	
t _{PLH} t _{PHL}	Propagation Delay	2.0			20	50		65		75	
	Time	4.5			5	10		13		15	ns
	(Qn - Qn+1)	6.0			4	9		11		13	
t _{PLH} t _{PHL}	Propagation Delay	2.0			48	145		180		220	
	Time	4.5			17	29		36		44	ns
	(CLOCK Q1)	6.0			13	25		31		38	
t _{PHL}	Propagation Delay	2.0			56	140		175		210	
	Time	4.5			18	28		35		42	ns
	(CLEAR - Qn)	6.0			15	24		30		36	
f _{MAX}	Maximum Clock	2.0		6.0	15		4.8		4		
	Frequency	4.5		30	65		24		20		MHz
		6.0		35	70		28		24		
t _{W(H)}	Minimum Pulse	2.0			40	75		95		110	
t _{W(L)}	Width (CLOCK)	4.5			8	15		19		22	ns
		6.0			7	13		16		19	
t _{W(H)}	Minimum Pulse	2.0			70	175		220		265	
. /	Width (CLEAR)	4.5			19	35		44		53	ns
		6.0			16	30		37		45	
t _{REM}	Minimum Removal	2.0				25		30		40	
	Time	4.5				5		6		8	ns
		6.0				5		5		7	

AC ELECTRICAL CHARACTERISTICS ($C_L = 50 \text{ pF}$, Input $t_r = t_f = 6 \text{ns}$)

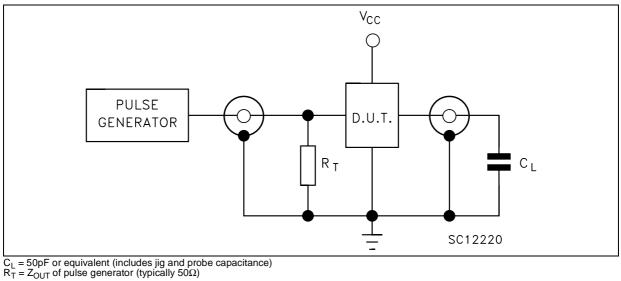
CAPACITIVE CHARACTERISTICS

		٦	Test Condition				Value				
Symbol Parameter	v _{cc}	V _{CC}		T _A = 25°C			-40 to 85°C		-55 to 125°C		
	(V)	Min.	Тур.	Max.	Min.	Max.	Min.	Max.			
C _{IN}	Input Capacitance	5.0			5	10		10		10	pF
C _{PD}	Power Dissipation Capacitance (note 1)	5.0			34						pF

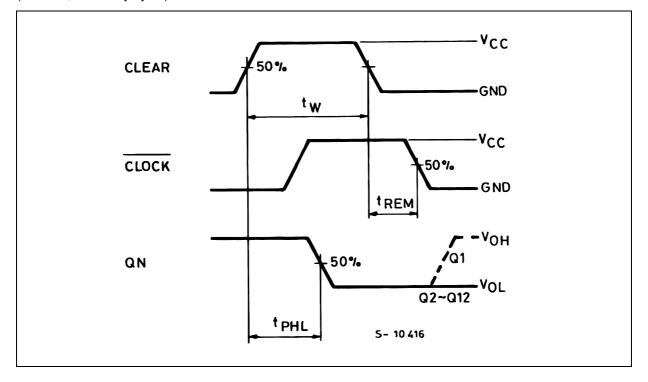
1) C_{PD} is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operating current can be obtained by the following equation. $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/2$ (per FLIP/ FLOP)

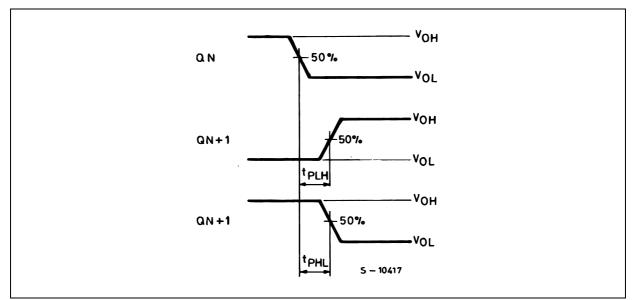


TEST CIRCUIT



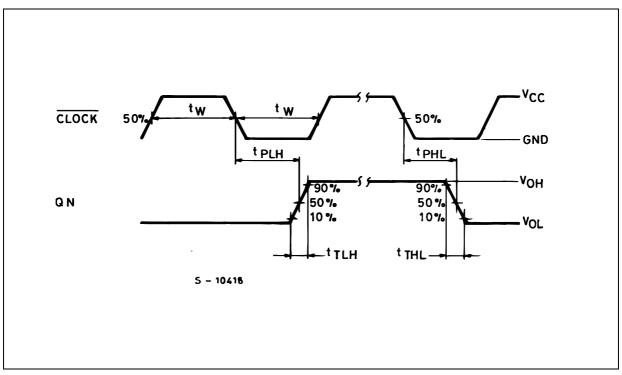
WAVEFORM 1: MINIMUM PULSE WIDTH (CLEAR) AND REMOVAL TIME (CLEAR TO CLOCK) (f=1MHz; 50% duty cycle)





WAVEFORM 2 : PROPAGATION DELAY TIME (f=1MHz; 50% duty cycle)

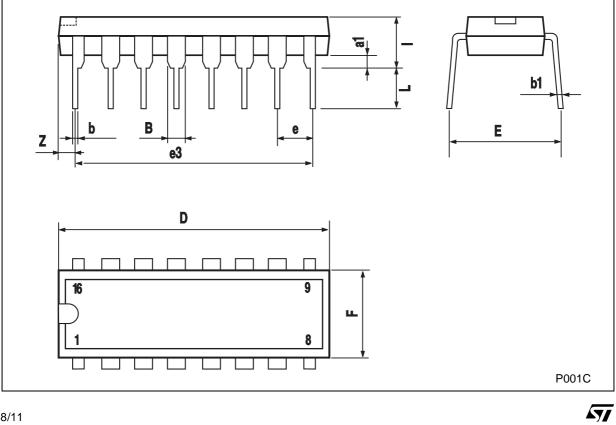
WAVEFORM 3 : PROPAGATION DELAY TIME, MINIMUM PULSE WIDTH (CLOCK)(f=1MHz; 50% duty cycle)



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	Plastic DIP-16 (0.25) MECHANICAL DATA										
DIM.		mm.		inch							
DIM.	MIN.	TYP	MAX.	MIN.	TYP.	MAX.					
a1	0.51			0.020							
В	0.77		1.65	0.030		0.065					
b		0.5			0.020						
b1		0.25			0.010						
D			20			0.787					
E		8.5			0.335						
е		2.54			0.100						
e3		17.78			0.700						
F			7.1			0.280					
I			5.1			0.201					
L		3.3			0.130						
Z			1.27			0.050					

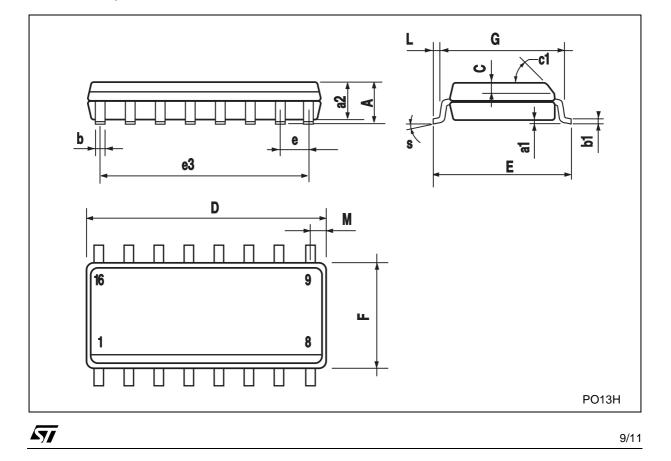
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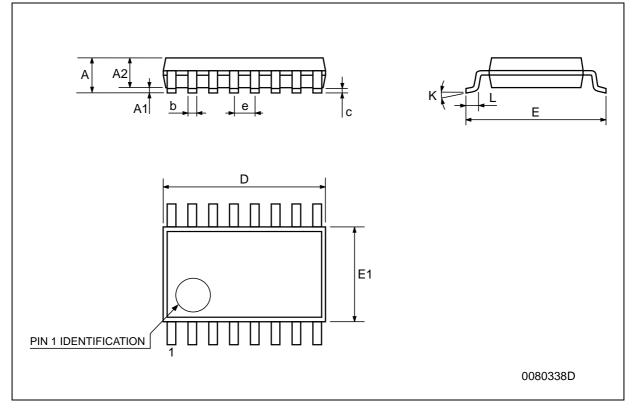
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DIM		mm.		inch					
DIM.	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.			
А			1.75			0.068			
a1	0.1		0.2	0.003		0.007			
a2			1.65			0.064			
b	0.35		0.46	0.013		0.018			
b1	0.19		0.25	0.007		0.010			
С		0.5			0.019				
c1		•	45°	(typ.)	•				
D	9.8		10	0.385		0.393			
Е	5.8		6.2	0.228		0.244			
е		1.27			0.050				
e3		8.89			0.350				
F	3.8		4.0	0.149		0.157			
G	4.6		5.3	0.181		0.208			
L	0.5		1.27	0.019		0.050			
М			0.62			0.024			





	TSSOP16 MECHANICAL DATA											
DIM.		mm.										
DIM.	MIN.	ТҮР	MAX.	MIN.	TYP.	MAX.						
А			1.2			0.047						
A1	0.05		0.15	0.002	0.004	0.006						
A2	0.8	1	1.05	0.031	0.039	0.041						
b	0.19		0.30	0.007		0.012						
С	0.09		0.20	0.004		0.0089						
D	4.9	5	5.1	0.193	0.197	0.201						
E	6.2	6.4	6.6	0.244	0.252	0.260						
E1	4.3	4.4	4.48	0.169	0.173	0.176						
е		0.65 BSC			0.0256 BSC							
К	0°		8°	0°		8°						
L	0.45	0.60	0.75	0.018	0.024	0.030						



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